

# Manasa Kaniselvan

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PhD candidate at ETH Zurich, originally from Canada. Working at the intersection of **semiconductor physics**, **high performance computing**, and **geometric deep learning** to advance large-scale semiconductor simulations at atomistic and *ab initio* levels of theory.

**Skills** - C++, Python (+PyTorch), high performance computing (CUDA/HIP, MPI, OpenMP), version control (git), scientific data visualization (Blender - intermediate), technical writing and presentation

## EDUCATION

### ETH Zurich

Candidate for PhD, Information Technology and Electrical Engineering

Zurich, Switzerland

November 2021–May 2026

### University of Waterloo

Master of Applied Science (MAsc), Electrical and Computer Engineering

Waterloo, ON, Canada

September 2019–May 2021

### University of Waterloo

Bachelor of Applied Science (BAsc), Nanotechnology Engineering.

Waterloo, ON, Canada

September 2014–May 2019

## EXPERIENCE

### Scientific Assistant & PhD Candidate - ETH Zürich

Advisor: Dr. Mathieu Luisier, Professor

Zürich, Switzerland

September 1<sup>st</sup> 2021 - 2026

- Developing multi-scale atomistic models for emerging memory devices, using methods such as Density Functional Theory (DFT), *ab initio* quantum transport, and Kinetic Monte Carlo. Incorporating equivariant graph neural networks to learn the electronic structure of individual material components, and adapting them for large-scale graphs which can describe structural disorder. Accelerating the developed codes on GPUs and multicore architectures.

### PhD Intern - Samsung Semiconductor Inc

Supervisor: Dr. Byounghak Lee, Principle Engineer

San Jose, CA, USA

May 15<sup>th</sup> 2023 - August 4<sup>th</sup> 2023

- Accelerated a large-scale semiconductor process/device code by developing an algorithm to leverage internal symmetries. Presented implementation and results to the Samsung Electronics applications team in Korea.

### Research Assistant & MAsc Student - University of Waterloo

Advisor: Dr. Youngki Yoon, Associate Professor

Waterloo, ON, Canada

September 1<sup>st</sup> 2019 - September 1<sup>st</sup> 2021

- Investigated transistor devices made from strain-engineered 2D materials using DFT and quantum transport methods. Collaborated with experimental partners to fabricate and test devices.

### Undergraduate Intern - Waterloo Institute for Nanotechnology

Supervisor: Dr. Dayan Ban, Professor

Waterloo, ON, Canada

January 1<sup>st</sup> 2018 - September 1<sup>st</sup> 2018

- Wrote a MATLAB code to simulate the operation of Resonant-Phonon Quantum Cascade Lasers (QCLs). Implemented global optimization methods to search for designs with higher-temperature lasing potential.

### Undergraduate Intern - Adaptive Surface Technologies

Supervisor: Dr. Tehila Nahum, Principle Engineer

Cambridge, MA, USA

September 1<sup>st</sup> 2016 - April 30<sup>th</sup> 2017

- AST develops slippery coatings by infusing nano-porous surfaces with lubricants. Worked in a team of three engineers to formulate a food-safe slippery container coating for one of the largest companies in the consumer packaging industry.

### Undergraduate Intern - National Institute of Materials Science

Supervisor: Dr. Genki Yoshikawa, Associate Professor

Tsukuba, Ibaraki, Japan

January 1<sup>st</sup> 2016 - April 1<sup>st</sup> 2016

- Optimized the morphology of drop-casted polymer films which served as active layers for a silicon nanosensor. Used COMSOL multiphysics to model sensor performance in the presence of film non-idealities.

## SELECTED AWARDS

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- NSERC PGSD-3 Doctoral Award (“Flexible Photovoltaics with 2D Material Heterostructures”) - 63,000 CAD 2021
- Sanford Fleming Foundation (SFF) Teaching Assistant Excellence Award - 500 CAD 2021
- Waterloo Dean’s Graduate Entrance Award - 5,000 CAD 2019
- NSERC Undergraduate Student Research Award (“Simulating semiconductor quantum structures”) - 4,000 CAD 2018
- NSERC Undergraduate Student Research Award (“Modeling quantum cascade lasers”) - 4,000 CAD 2017

## TEACHING & SUPERVISION

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### Lectures

- **(Guest lecturer) Brain Inspired Computing: From Devices to Applications, ETH Zurich** April 2024  
Designed and delivered a lecture on device simulation approaches for non-volatile resistive memory.
- **(Co-Lecturer) Digital Electronics, Ashesi University (in collaboration with ETH Zurich)** February 2024  
Primary lecturer for a 2-week block-course on Digital Electronics held as part of the ETH-Ashesi collaborative Masters program in Ghana. Served as a technical interviewer for applicants of the following cohort.

### Student Project Supervisions

At ETH, masters’ students can undertake semester- and thesis-projects proposed and led by PhD candidates. I have supervised 4 semester projects (for which students work 4 months part-time), and 2 theses (6 months full time).

- **Masters’ thesis of Rayen Mahjoub, ETH Zurich** September 2024 - March 2025  
Adapting equivariant graph neural networks for electronic structure prediction of phase-change materials.
- **Masters’ thesis of Alexander Maeder, ETH Zurich** September 2023 - March 2024  
Distributing iterative solvers for a GPU-accelerated Kinetic Monte Carlo code. Co-supervised with Dr. Alexandros Ziogas and Vincent Maillou. (*\*Thesis awarded the ETH Medal*)
- **Masters’ thesis of Jente Clarysse, ETH Zurich** April 2023 - October 2023  
Developing simulations of thermally-activated switching in resistive memory. (*\*Thesis awarded the ETH Medal*)
- **Masters’ semester project of Jente Clarysse, ETH Zurich** September 2022 - January 2023  
Developing a graph-based model of current flow through atomistic structures.
- **Masters’ semester project of Zhouyang Yu, ETH Zurich** September 2022 - January 2023  
Performing quantum transport simulations on Interband Cascade Lasers (ICLs). Co-supervised with Prof. Matheiu Luisier.
- **Bachelor thesis of Patrik Gjini, ETH Zurich** February 2022 - May 2022  
Implemented a Fast Multipole Method algorithm for Poisson’s equation. Co-supervised with Dr. Marko Mladenovic.
- **Masters’ semester project of Patrick Büttler, ETH Zurich** February 2022 - May 2022  
Investigating resistive switching in MoTe<sub>2</sub> with *ab-initio* Molecular Dynamics. Co-supervised with Jonathan Backmann.

### Student Design Team Positions

- **Technical Lead - UW Nano Robotics Group (UWNRG)** Waterloo, ON, Canada  
January 2015 - July 2019
  - UWNRG is an undergraduate student design team which designs micro-robotic actuation systems to compete at the annual IEEE International Conference for Robotics and Automation (ICRA) Microbotics Challenges.
  - Led the development of the microbot SAM (Solenoid Actuated Microbot). Completing the competition challenges required cleanroom fabrication work, electrical setup, and basic image recognition/pathfinding.
  - Acquired funding for lab expenses, equipment, cleanroom usage, and conference travel costs. Competition Record: 3rd place (ICRA 2015, Seattle USA), 1st place (ICRA 2016, Stockholm Sweden), 2nd place (ICRA 2018, Brisbane Australia).

‘\*’ = equal contribution

## Under Review:

1. C. Xia\*, **M. Kaniselvan\***, A. Ziogas, M. Mladenović, A. Maeder+, and M. Luisier, “Learning the Hamiltonians of Disordered Materials with Equivariant Graph Networks”. Submitted to the *[anonymized for double blind review]*.
2. **M. Kaniselvan**, Y. Jeon, M. Mladenović, M. Luisier, and D. Akinwande, “Mechanisms of Resistive Switching in 2D Layered Materials”. Under review at *Nature Materials*.

## Published:

3. **M. Kaniselvan\***, A. Maeder\*, M. Mladenovic, M. Luisier, A. Ziogas, “Accelerated Kinetic Monte Carlo Simulations of Atomistically-Resolved Resistive Memory Arrays”. (accepted) *International Conference for High Performance Computing, Networking, Storage, and Analysis (SC24)*, November 2024
4. M. Luisier, J. Backman, J. Cao, L. Deuschle, **M. Kaniselvan**, Y. Lee, A. Maeder, V. Maillou, M. Mladenovic, N. Vetsch, A. Winka, C. H. Xia, and A. N. Ziogas, “Nanoscale Device Modeling beyond the Ballistic Limit of Transport and Fixed Geometries”. *IEEE International Electron Device Meeting (IEDM)*, December 2024.
5. C. Weilenmann, A. Ziogas, T. Zellweger, K. Portner, M. Mladenović, **M. Kaniselvan**, T. Moraitis, M. Luisier, A. Emboras, “Single Neuromorphic Memristor closely Emulates Multiple Synaptic Mechanisms for Energy Efficient Neural Networks”. *Nature Communications*, August 2024. doi: 10.1038/s41467-024-51093-3 (**\*Editor’s Pick**)
6. **M. Kaniselvan**, M. Mladenović, J. Clarysse, and M. Luisier, “Insights behind multi-level conductance transitions in HfO<sub>x</sub> memristors”. *Device Research Conference (DRC)*, June 2024.
7. Alexander Maeder, **Manasa Kaniselvan**, Marko Mladenovic, Mathieu Luisier and Alexandros Nikolaos Ziogas, “A Distributed Conjugate Gradient Solver for Kinetic Monte Carlo simulations under applied fields.” *Platform for Advanced Scientific Computing (PASC24)*, June 2024. Poster.
8. M. Sritharan, R.K.A Bennett, **M. Kaniselvan**, and Y. Yoon, “A Comparative Study on 2D Materials with Native High-Oxides for Ultrascaled Transistors”, *Materials Today Electronics*, March 2024. doi:10.1016/j.mtelec.2024.100096
9. Marko Mladenovic, **Manasa Kaniselvan**, Christoph Weilenmann, Alexandros Emboras, and Mathieu Luisier “Termination-Dependence of Resistive Switching in SrTiO<sub>3</sub>-based Valence Change Memory.” *International Workshop on Computational Nanotechnology (IWCN)*, June 2023.
10. **M. Kaniselvan**, M. Luisier, and M. Mladenovic, “Atomistic Modelling of Field-Induced Resistive Switching in Valence Change Memory,” *ACS Nano*, April 2023. doi: 10.1021/acsnano.2c12575 (**\*Journal Cover Article**)

**In the media:** [Covered by ETH] [Covered by the Werner Siemens Foundation]

11. H. Park\*, A. Sen\*, **M. Kaniselvan**, A. AlMutairi, A. Bal, L. Lee, Y. Yoon, and S. Kim, “Wafer-scale Nanoporous 2D Active Pixel Image Sensor Matrix with Highly Uniformity, High Sensitivity, and Rapid Switching,” *Advanced Materials*, February 2023. doi: 10.1002/adma.202210715
12. **M. Kaniselvan**, M. Luisier, and M. Mladenovic, “An Atomistic Modelling Framework for Valence Change Memory Cells,” *Solid State Electronics: LETTERS from the International Conference on Simulation of Semiconductor Processes and Devices (SISPAD)*, October 2022 doi: 10.1063/2F5.0053789.
13. **M. Kaniselvan**, M. Sritharan, and Y. Yoon, “Mitigating Tunneling Leakage in Ultrascaled HfS<sub>2</sub> pMOS Devices with Uniaxial Strain,” *IEEE Electron Device Letters*, June 2022 doi:10.1109/LED.2022.3179228 (**\*Editor’s Pick**)
14. **M. Kaniselvan** and Y. Yoon, “Strain-tuning PtSe<sub>2</sub> for high ON-current lateral tunnel field-effect transistors,” *Applied Physics Letters*, vol. 119, no. 7, p. 073102, Aug. 2021. doi:10.1063/2F5.0053789
15. G. Han, **M. Kaniselvan**, and Y. Yoon, “Photoresponse of MoSe<sub>2</sub> Transistors: A Fully Numerical Quantum Transport Simulation Study,” *ACS Applied Electronic Materials*, vol. 2, no. 11, pp. 3765–3772, Nov. 2020. doi:10.1021/acsaelm.0c00795
16. M. Naqi\*, **M. Kaniselvan\***, S. Choo\*, G. Han, S. Kang, J. Kim, Y. Yoon, and S. Kim, “Ultrasensitive Multilayer MoS<sub>2</sub>-Based Photodetector with Permanently Grounded Gate Effect,” *Advanced Electronic Materials*, vol. 6, no. 4, p. 1901256, Feb. 2020. doi: 10.1002/aelm.201901256.